NSN 5961-00-403-2561

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-403-2561
Inclosure Material:
Metal
Overall Length:
0.658 inches
Terminal Length:
0.630 inches
Overall Height:
0.150 inches
Overall Width:
0.490 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.332 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 working peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
8.00 amperes source cutoff current preset and 80.00 amperes source cutoff current absolute
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector outside diameter
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0